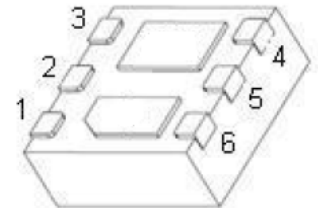


**DFNWB2×2-6L Plastic-Encapsulat MOSFETS****CJMPD11** Dual P-Channel Power MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}$ TYP	I_D
-20V	70mΩ@-4.5 V	-2.3 A
	110mΩ@-2.5 V	

DFNWB2×2-6L**General Description**

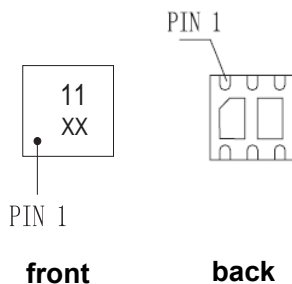
The CJMPD11 uses advanced trench technology and design to Provide excellent $R_{DS(on)}$ with low gate charge. This device is suitable for use in DC-DC conversion applications.

FEATURE

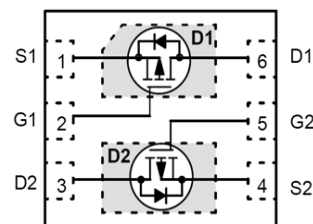
- Low Profile for Easy Fit in Thin Environments
- Bidirectional Current Folw with Common Source Configuration

APPLICATIONS

- Optimized for Battery and Load Management Applications in Portable Equipment
- Li-Ion Battery Charging and Protection Circuits
- High Power Management in Portable , Battery Powered Products
- High Side Load Switch

MARKING:

11 = Part No.
Solid dot = Pin1 indicator.
XX = Code.

Equivalent Circuit**Maximum ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)**

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 8	V
Continuous Drain Current	I_D	-2.3	A
Pulsed Drain Current ($t=300\mu\text{s}$)	I_{DM}	-10	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^{\circ}\text{C/W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}\text{C}$

MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25^{\circ}\text{C}$ unless otherwise specified

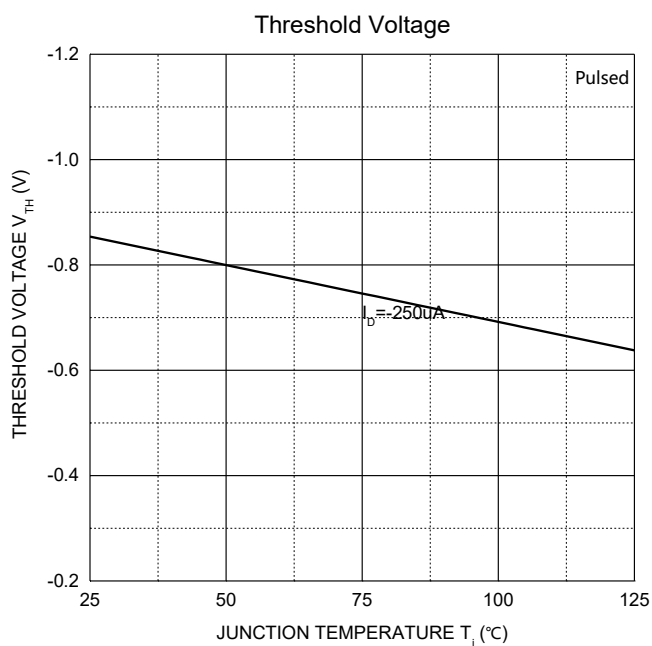
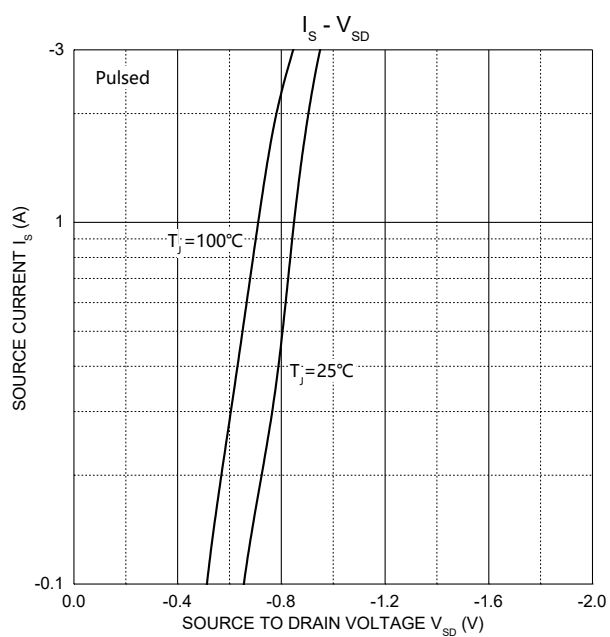
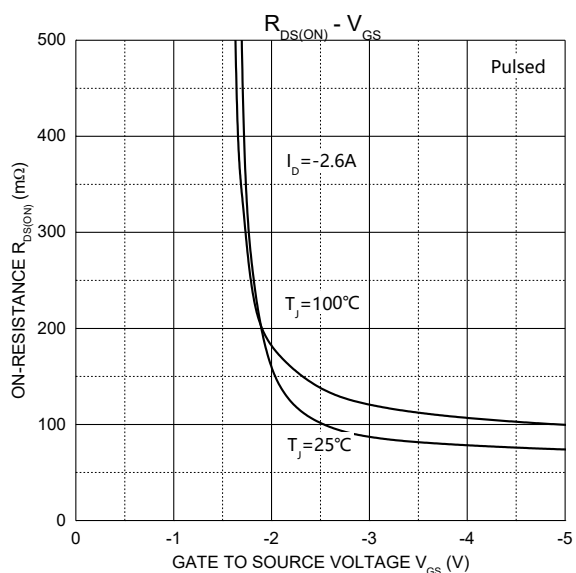
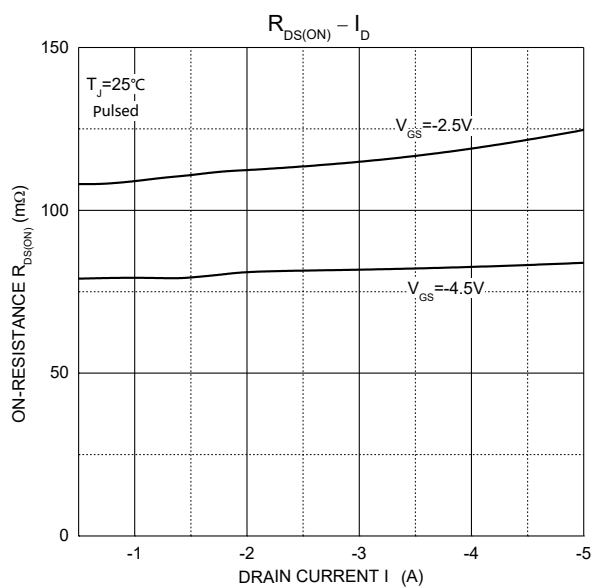
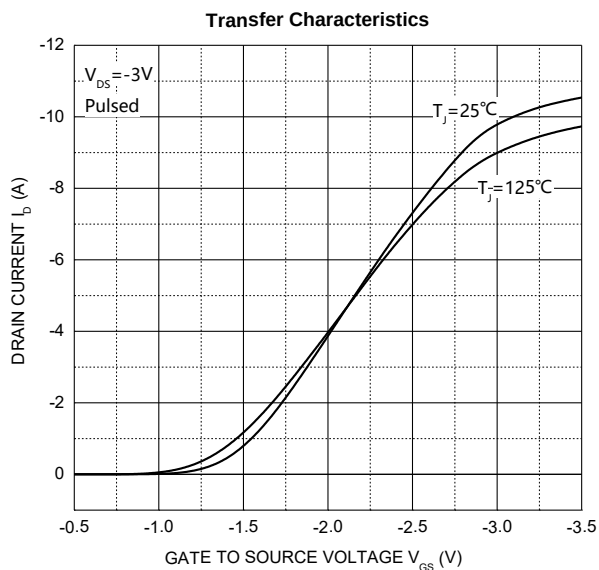
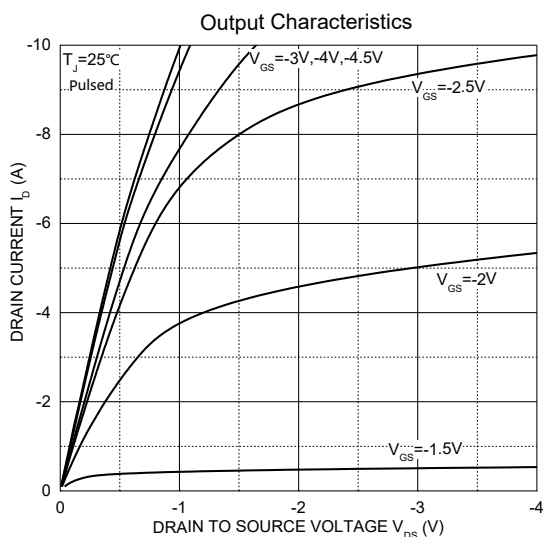
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	-20			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-16V, V _{GS} = 0V			-1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±8V, V _{DS} = 0V			±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.4	-0.7	-1	V
Drain-source on-resistance ^a	R _{DS(on)}	V _{GS} =-4.5V, I _D =-3A		70	110	mΩ
		V _{GS} =-2.5V, I _D =-2A		110	140	
Forward tranconductance ^a	g _{FS}	V _{DS} =-5V, I _D =-2A	5			S
Dynamic characteristics ^b						
Input Capacitance	C _{iss}	V _{DS} =-10V, V _{GS} =0V, f =1MHz		405		pF
Output Capacitance	C _{oss}			75		
Reverse Transfer Capacitance	C _{rss}			55		
Gate resistance	R _g	f =1MHz		6		Ω
Total Gate Charge	Q _g	V _{DS} =-10V, V _{GS} =-2.5V, I _D =-3A		3.3	12	nC
Gate-Source Charge	Q _{gs}			0.7		
Gate-Drain Charge	Q _{gd}			1.3		
Turn-on delay time	t _{d(on)}	V _{DD} =-10V, V _{GEN} =-4.5V, I _D =-1A R _L =10Ω, R _{GEN} =1Ω		11		ns
Turn-on rise time	t _r			35		
Turn-off delay time	t _{d(off)}			30		
Turn-off fall time	t _f			10		
Source-Drain Diode characteristics						
Diode forward current	I _S	T _C =25℃			-2.3	A
Diode pulsed forward current ^a	I _{SM}				-10	A
Diode Forward voltage	V _{DS}	V _{GS} =0V, I _S =-1.3A			-1.2	V

Notes :

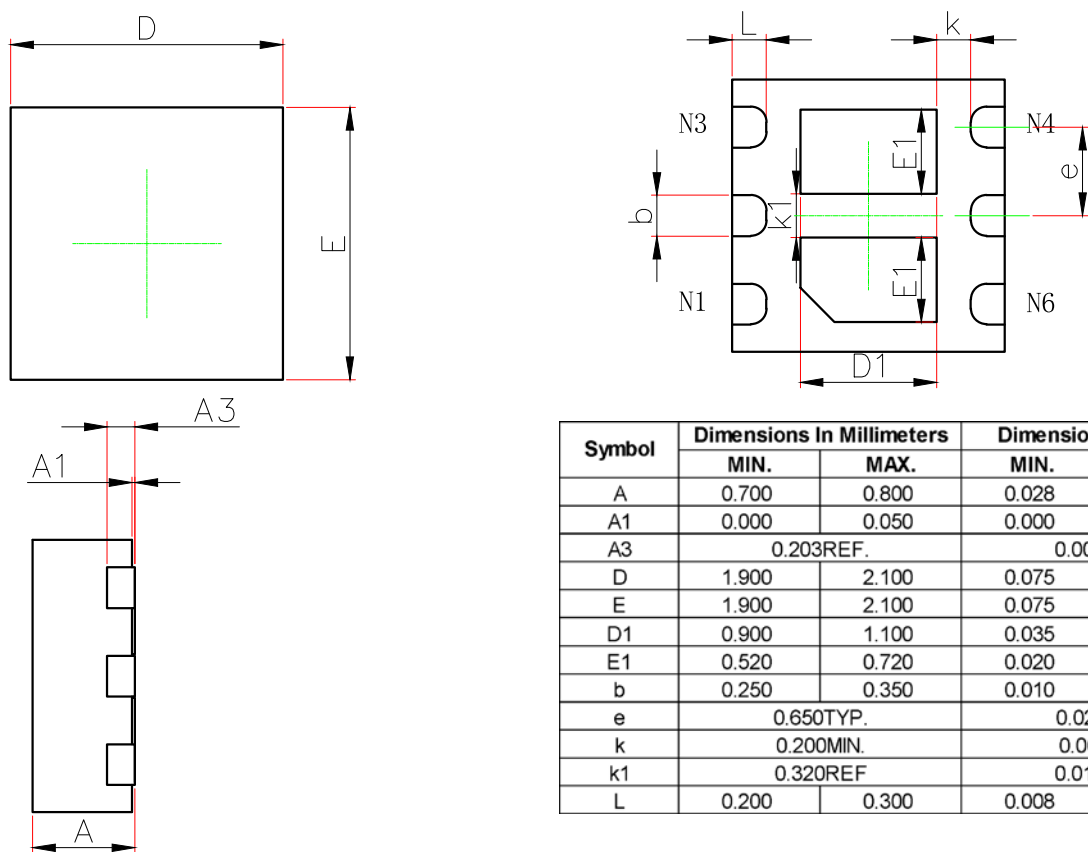
a.Pulse Test : Pulse Width < 300 μ s, Duty Cycle $\leq$ 2%.

b.Guaranteed by design, not subject to production testing.

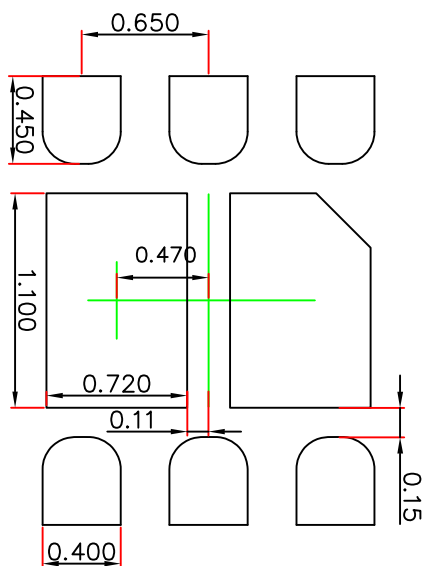
Typical Characteristics



DFNWB2X2-6L Package Outline Dimensions



DFNWB2X2-6L Suggested Pad Layout

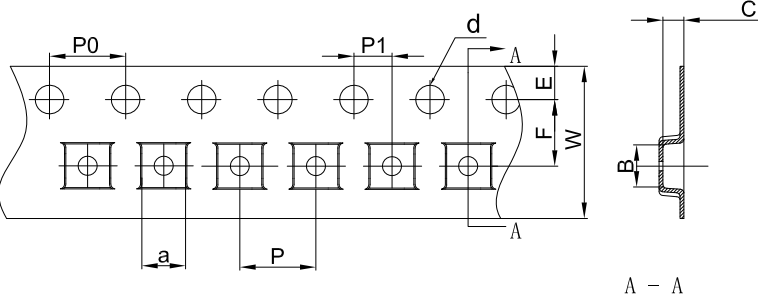


Note:
1.Controlling dimension:in millimeters.
2.General tolerance:±0.050mm.
3.The pad layout is for reference purposes only.

NOTICE
JSCJ reserves the right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

DFNWB2X2-6L Tape and Reel

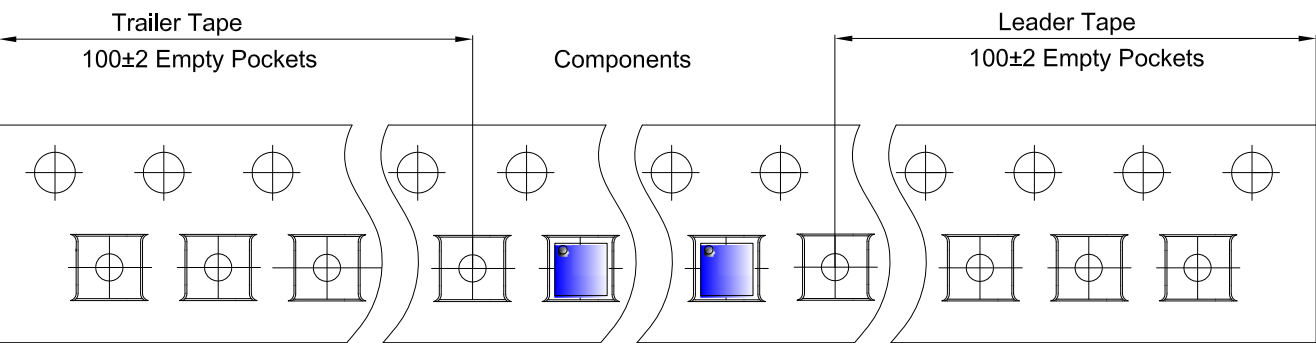
DFNWB2×2-6L Embossed Carrier Tape



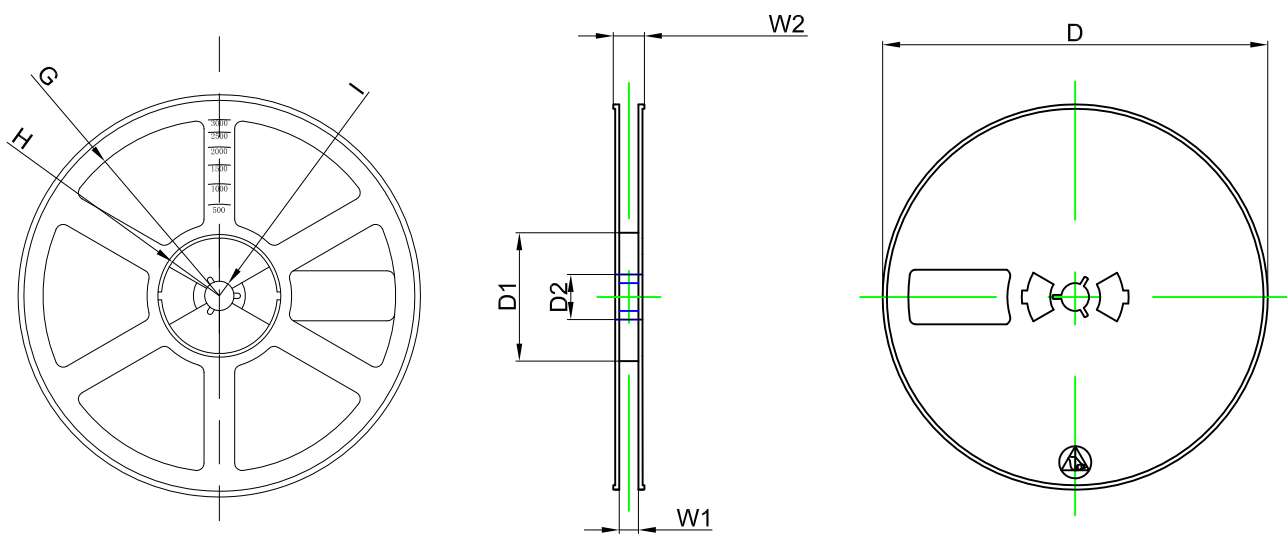
Packaging Description:
DFNWB2×2-6L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 18.0cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
DFNWB2×2-6L	2.30	2.30	1.10	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

DFNWB2×2-6L Tape Leader and Trailer



DFNWB2×2-6L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	